NSN 5961-01-388-1370

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T0-111

Features Provided:

High power

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

5.00 amperes zero-gate-voltage source current blank

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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